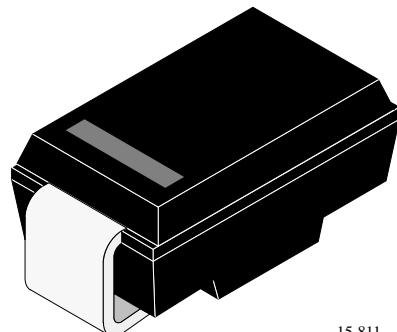


Silicon Transient Voltage Suppressors

Features

- Glass passivated junction
- High reliability
- Stand-off voltage range 8.2V to 220V
- Excellent clamping capability
- Fast response time (typ. $\leq 1\text{ps}$ from 0 to $V_{Z\min}$)



15 811

Applications

- Protection from high voltage, high energy transients

Order Instruction

Type	Ordering Code	Remarks
BZG04-8V2	BZG04-8V2-TR	Tape and Reel (1.500 pcs)
BZG04-8V2	BZG04-8V2-TR3	Tape and Reel (6.000 pcs)

Absolute Maximum Ratings

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Symbol	Value	Unit
Power dissipation	$R_{thJA} < 25 \text{ K/W}, T_{amb} = 100^\circ\text{C}$	P_V	3	W
	$R_{thJA} < 100 \text{ K/W}, T_{amb} = 50^\circ\text{C}$	P_V	1.25	W
Non repetitive peak surge power dissipation	$t_p = 10/1000\mu\text{s}, T_j = 25^\circ\text{C}$ prior to surge	P_{ZSM}	300	W
Peak forward surge current	10 ms single half sine wave	I_{FSM}	50	A
Junction temperature		T_j	175	$^\circ\text{C}$
Storage temperature range		T_{stg}	-65...+150	$^\circ\text{C}$

Maximum Thermal Resistance

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Symbol	Value	Unit
Junction lead		R_{thJL}	25	K/W
Junction ambient	mounted on epoxy-glass hard tissue, Fig. 1a	R_{thJA}	150	K/W
	mounted on epoxy-glass hard tissue, Fig. 1b		125	
	mounted on Al-oxid-ceramic (Al_2O_3), Fig. 1b		100	

Electrical Characteristics

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Forward voltage	$I_F = 0.5\text{A}$	V_F			1.2	V

BZG04...**Vishay Semiconductors**

Type	Standoff Voltage		Breakdown Voltage $V_{(BR)}$ at I_R		TK V_Z at I_R		Clamping Voltage $V_{CL(R)}$ at I_{PP}	
	V_R V	I_R μ A	V	mA	%/K	%/K	V *)	A *)
			Max.	Min.	Typ.	Max.	Max.	
8V2	8.2	20	9.4	50	0.05	0.09	14.8	20.3
9V1	9.1	5	10.4	50	0.05	0.10	15.7	19.1
10	10	5	11.4	50	0.05	0.10	17.0	17.7
11	11	5	12.4	50	0.05	0.10	18.9	15.9
12	12	5	13.8	50	0.05	0.10	20.9	14.4
13	13	5	15.3	50	0.06	0.11	22.9	13.1
15	15	5	16.8	25	0.06	0.11	25.6	11.7
16	16	5	18.8	25	0.06	0.11	28.4	10.6
18	18	5	20.8	25	0.06	0.11	31.0	9.7
20	20	5	22.8	25	0.06	0.11	33.8	8.9
22	22	5	25.1	25	0.06	0.11	38.1	7.9
24	24	5	28	25	0.06	0.11	42.2	7.1
27	27	5	31	25	0.06	0.11	46.2	6.5
30	30	5	34	25	0.06	0.11	50.1	6.0
33	33	5	37	10	0.06	0.11	54.1	5.5
36	36	5	40	10	0.07	0.12	60.7	4.9
39	39	5	44	10	0.07	0.12	65.5	4.6
43	43	5	48	10	0.07	0.12	70.8	4.2
47	47	5	52	10	0.07	0.12	78.6	3.8
51	51	5	58	10	0.08	0.13	86.5	3.5
56	56	5	64	10	0.08	0.13	94.4	3.2
62	62	5	70	10	0.08	0.13	103.5	2.9
68	68	5	77	10	0.08	0.13	114	2.6
75	75	5	85	10	0.09	0.13	126	2.4
82	82	5	94	5	0.09	0.13	139	2.2
91	91	5	104	5	0.09	0.13	152	2.0
100	100	5	114	5	0.09	0.13	167	1.8
110	110	5	124	5	0.09	0.13	185	1.6
120	120	5	138	5	0.09	0.13	204	1.5
130	130	5	153	5	0.09	0.13	224	1.3
150	150	5	168	5	0.09	0.13	249	1.2
160	160	5	188	5	0.09	0.13	276	1.1
180	180	5	208	5	0.09	0.13	305	1.0
200	200	5	228	2	0.09	0.13	336	0.9
220	220	5	251	2	0.09	0.13	380	0.8

*) 10/1000 μ s pulse

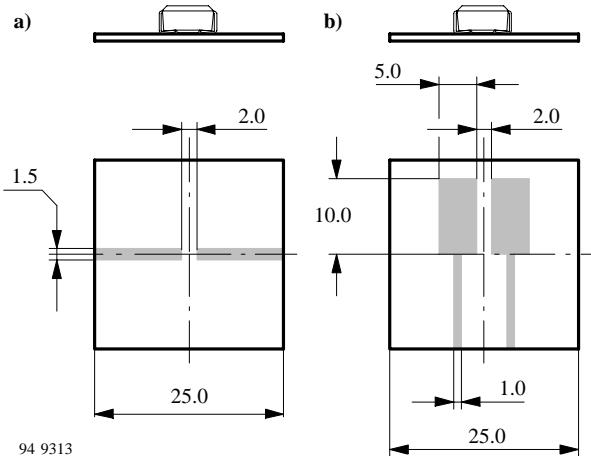
Characteristics ($T_j = 25^\circ\text{C}$, unless otherwise specified)


Figure 1. Boards for R_{thJA} definition (copper overlay 35μ)

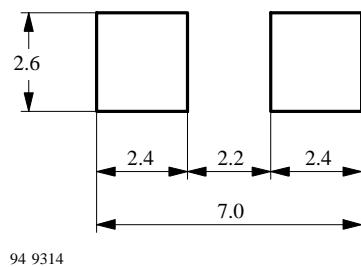


Figure 2. Recommended foot pads (in mm)

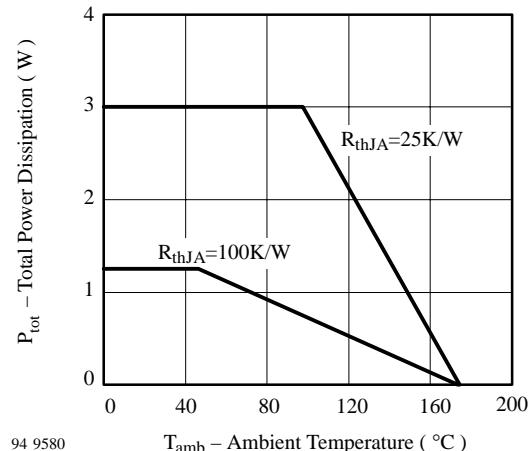


Figure 3. Total Power Dissipation vs. Ambient Temperature

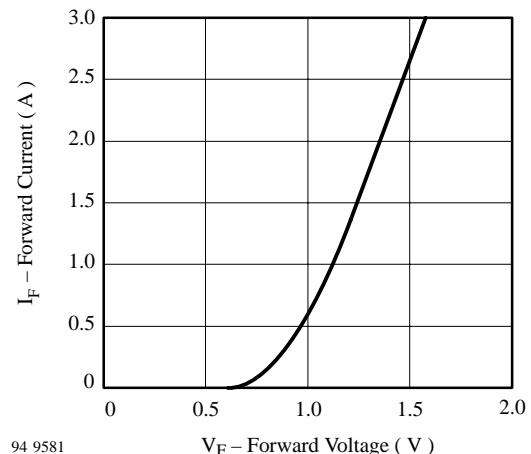
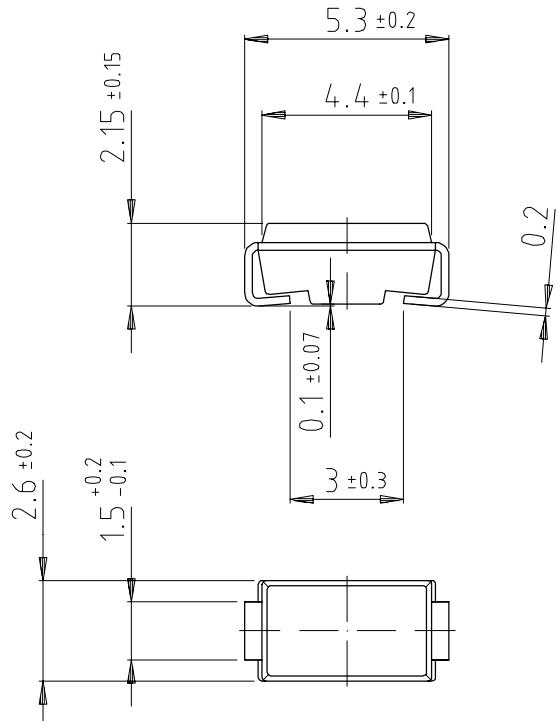
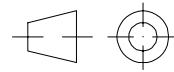


Figure 4. Forward Current vs. Forward Voltage

Dimensions in mm

Plastic case JEDEC DO 214
similar to SMA
Cathode indicated by a band

14275



technical drawings
according to DIN
specifications



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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